Shunt Regulator

HITACHI

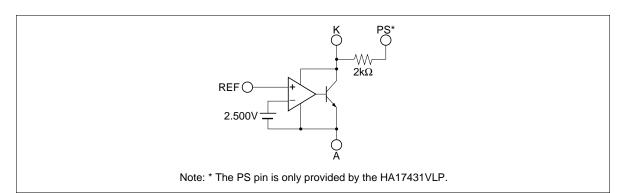
Description

The HA17431 series is a family of voltage referenced shunt regulators. The main application of these products is in voltage regulators that provide a variable output voltage. The HA17431 series products are provided in a wide range of packages; TO-92 and TO-92MOD insertion mounting packages and MPAK-5, UPAK, and FP-8D surface mounting packages are available. The on-chip high-precision reference voltage source can provide $\pm 1\%$ accuracy in the V versions, which have a V_{KA} max of 16 volts. The HA17431VLP, which is provided in the MPAK-5 package, is designed for use in switching mode power supplies. It provides a built-in photocoupler bypass resistor for the PS pin, and an error amplifier can be easily constructed on the supply side.

Features

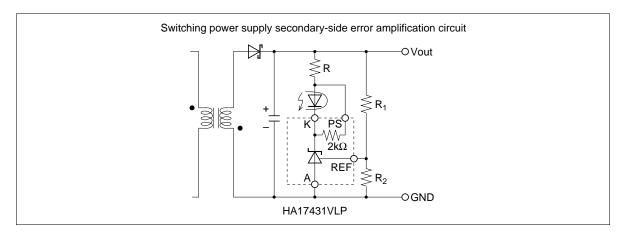
- The V versions provide 2.500 V $\pm 1\%$ at Ta = 25°C
- The HA17431VLP includes a photocoupler bypass resistor (2 k Ω)
- The reference voltage has a low temperature coefficient
- The MPAK-5 and UPAK miniature packages are optimal for use on high mounting density circuit boards
- A wide operating temperature range (-40 to +85°C) is provided by the TO-92, TO-92MOD, and FP-8D package versions

Block Diagram





Application Circuit Example



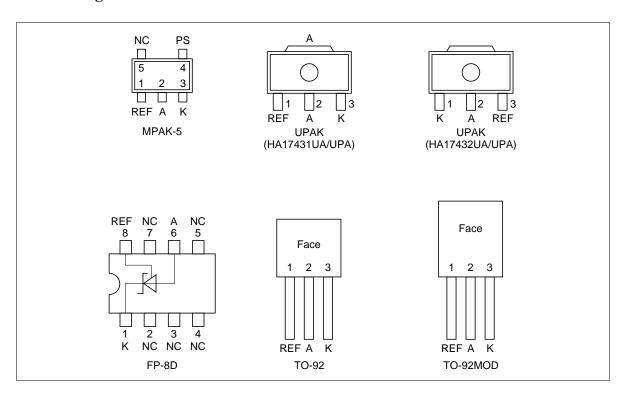
Ordering Information

		Version				
Item		V Version	A Version	Normal Version	Package	Temp. Range
Reference	Accuracy	±1% (at 25°C)	±2.2%	±4%		_
voltage	Max	2.525 V	2.550 V	2.595 V	-	
	Тур	2.500 V	2.495 V	2.495 V	-	
	Min	2.475 V	2.440 V	2.395 V	-	
Cathode volta	age	16 V max	40 V max	40 V max	-	
Cathode curr	ent	50 mA max	150 mA max	150 mA max		
Wide temper	ature use	HA17431VPJ	HA17431PNAJ		TO-92	−40 to +85°C
			HA17431PAJ		TO-92MOD	-
				HA17431PJ	TO-92MOD	
			HA17431FPAJ		FP-8D	-
				HA17431FPJ	FP-8D	-

Ordering Information (cont)

	Version					
Item	V Version	A Version	Normal Version	- Package	Temp. Range	
Industrial use	HA17431VLP			MPAK-5	−20 to +85°C	
	HA17431VP	HA17431PNA		TO-92		
		HA17431UPA		UPAK	-	
		HA17432UPA		UPAK	-	
		HA17431PA		TO-92MOD	-	
			HA17431P	TO-92MOD	-	
		HA17431FPA		FP-8D	-	
			HA17431FP	FP-8D	-	
Commercial use		HA17431UA		UPAK	-	
		HA17432UA		UPAK	-	

Pin Arrangement



HITACHI

Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	HA17431VLP	HA17431VP	HA17431VPJ	Unit	Notes
Cathode voltage	V_{KA}	16	16	16	V	1
PS term. voltage	V_{PS}	V _{KA} to 16	_	_	٧	1, 2, 3
Continuous cathode current	I _K	-50 to +50	-50 to +50	-50 to +50	mA	_
Reference input current	Iref	-0.05 to +10	-0.05 to +10	-0.05 to +10	mA	
Power dissipation	P_T	150 *4	500 * ⁵	500 * ⁵	mW	4, 5
Operating temperature range	Topr	-20 to +85	-20 to +85	-40 to +85	°C	_
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	°C	

Item	Symbol	HA17431P/PA	HA17431FP/FPA	HA17431UA/UPA	Unit	Notes
Cathode voltage	V_{KA}	40	40	40	V	1
Continuous cathode current	I _K	-100 to +150	-100 to +150	-100 to +150	mA	
Reference input current	Iref	-0.05 to +10	-0.05 to +10	-0.05 to +10	mA	
Power dissipation	P _T	800 *6	500 * ⁷	800 *8	mW	6, 7, 8
Operating temperature range	Topr	-20 to +85	-20 to +85	–20 to +85	°C	
Storage temperature	Tstg	-55 to +150	-55 to +125	-55 to +150	°C	

Item	Symbol	HA17431PJ/PAJ	HA17431FPJ/FPAJ	Unit	Notes
Cathode voltage	V_{KA}	40	40	V	1
Continuous cathode current	I _K	-100 to +150	-100 to +150	mA	
Reference input current	Iref	-0.05 to +10	-0.05 to +10	mA	
Power dissipation	P _T	800 *6	500 * ⁷	mW	6, 7
Operating temperature range	Topr	-40 to +85	-40 to +85	°C	
Storage temperature	Tstg	–55 to +150	-55 to +125	°C	

Item	Symbol	HA17432UA/UPA	HA17431PNA	HA17431PNAJ	Unit	Notes
Cathode voltage	V_{KA}	40	40	40	V	
Continuous cathode current	I _K	-100 to +150	-100 to +150	-100 to +150	mA	
Reference input current	Iref	-0.05 to +10	-0.05 to +10	-0.05 to +10	mA	
Power dissipation	P _T	800 *8	500 * ⁵	500* ⁵	mW	
Operating temperature range	Topr	-20 to +85	–20 to +85	-40 to +85	°C	
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	°C	

Notes: 1. Voltages are referenced to anode.

- 2. The PS pin is only provided by the HA17431VLP.
- 3. The PS pin voltage must not fall below the cathode voltage. If the PS pin is not used, the PS pin is recommended to be connected with the cathode.
- 4. Ta \leq 25°C. If Ta > 25°C, derate by 1.2 mW/°C.
- 5. Ta \leq 25°C. If Ta > 25°C, derate by 4.0 mW/°C.
- 6. Ta \leq 25°C. If Ta > 25°C, derate by 6.4 mW/°C.
- 7. 50 mm \times 50 mm \times t1.5mm glass epoxy board, Ta \leq 25°C. If Ta > 25°C, derate by 5 mW/°C.
- 15 mm × 25 mm × t0.7mm alumina ceramic board,Ta ≤ 25°C. If Ta > 25°C, derate by 6.4 mW/°C.

Electrical Characteristics (Ta = 25° C)

$\textbf{HA17431VLP/VP/VPJ} \; (Ta = 25^{\circ}\text{C}, \, I_{K} = 10 \; \text{mA})$

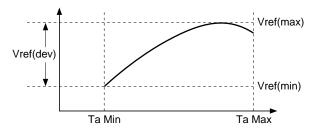
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	Notes
Reference voltage	Vref	2.475	2.500	2.525	V	V _{KA} = Vref	
Reference voltage temperature deviation	Vref(dev)	_	10	_	mV	$V_{KA} = Vref,$ $Ta = -20^{\circ}C \text{ to } +85^{\circ}C$	1
Reference voltage temperature coefficient	∆Vref/∆Ta	_	±30	_	ppm/°C	V _{KA} = Vref, 0°C to 50°C gradient	
Reference voltage regulation	$\Delta \text{Vref}/\Delta \text{V}_{\text{KA}}$	_	2.0	3.7	mV/V	V _{KA} = Vref to 16 V	
Reference input current	Iref	_	2	6	μΑ	$R_1 = 10 \text{ k}\Omega, R_2 = \infty$	
Reference current temperature deviation	Iref(dev)	_	0.5	_	μА	$R_1 = 10 \text{ k}\Omega, R_2 = \infty,$ $Ta = -20^{\circ}\text{C to } +85^{\circ}\text{C}$	
Minimum cathode current	Imin	_	0.4	1.0	mA	V _{KA} = Vref	2
Off state cathode current	loff	_	0.001	1.0	μΑ	V _{KA} = 16 V, Vref = 0 V	
Dynamic impedance	Z _{KA}	_	0.2	0.5	Ω	$V_{KA} = Vref,$ $I_{K} = 1 \text{ mA to } 50 \text{ mA}$	
Bypass resistance	R _{PS}	1.6	2.0	2.4	kΩ	I _{PS} = 1 mA	3
Bypass resistance temperature coefficient	$\Delta R_{PS}/\Delta Ta$	_	+2000	_	ppm/°C	I _{PS} = 1 mA, 0°C to 50°C gradient	3

HA17431PJ/PAJ/FPJ/FPAJ/P/PA/UA/UPA/FP/FPA/PNA/PNAJ, HA17432UA/UPA

 $(Ta = 25^{\circ}C, I_K = 10 \text{ mA})$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions		Notes
Reference voltage	Vref	2.440	2.495	2.550	V	$V_{KA} = Vref$		А
	•	2.395	2.495	2.595	_			Normal
Reference voltage temperature deviation	Vref(dev)	_	11	(30)	mV	V _{KA} = Vref	Ta = -20°C to +85°C	1, 4
		_	5	(17)	_		Ta = 0°C to +70°C	1, 4
Reference voltage	ΔV ref/ ΔV_{KA}	_	1.4	3.7	mV/V	V _{KA} = Vref to 10 V		
regulation		_	1	2.2	_	V _{KA} = 10 V to 40 V		
Reference input current	Iref	_	3.8	6	μΑ	$R_1 = 10 \text{ k}\Omega$, R ₂ = ∞	
Reference current temperature deviation	Iref(dev)	_	0.5	(2.5)	μА	$R_1 = 10 \text{ k}\Omega, R_2 = \infty,$ $Ta = 0^{\circ}\text{C to } +70^{\circ}\text{C}$		4
Minimum cathode current	Imin	_	0.4	1.0	mA	V _{KA} = Vref		2
Off state cathode current	loff	_	0.001	1.0	μΑ	$V_{KA} = 40 \text{ V},$	Vref = 0 V	
Dynamic impedance	Z _{KA}	_	0.2	0.5	Ω	$V_{KA} = Vref,$ $I_K = 1 mA to$	o 100 mA	

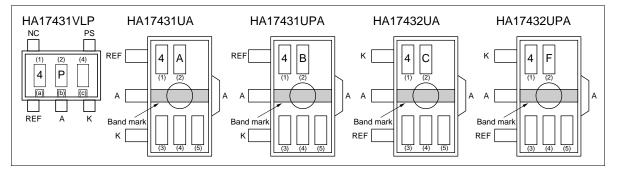
Notes: 1. Vref(dev) = Vref(max) - Vref(min)



- 2. Imin is given by the cathode current at Vref = $Vref_{(IK=10mA)} 15 \text{ mV}$.
- 3. R_{PS} is only provided in HA17431VLP.
- 4. The maximum value is a design value (not measured).

MPAK-5 and UPAK Marking Patterns

The marking patterns shown below are used on MPAK-5 and UPAK products. Note that the product code and mark pattern are different. The pattern is laser-printed.



Notes: 1. Boxes (1) to (5) in the figures show the position of the letters or numerals, and are not actually marked on the package.

2. The letters (1) and (2) show the product specific mark pattern.

Product	(1)	(2)
HA17431VLP	4	P
HA17431UA	4	A
HA17431UPA	4	В
HA17432UA	4	С
HA17432UPA	4	F

- 3. The letter (3) shows the production year code (the last digit of the year) for UPAK products.
- 4. The bars (a), (b) and (c) show a production year code for MPAK-5 products as shown below. After 2005 the code is repeated every 8 years.

		•	, ,						
Year	1997	1998	1999	2000	2001	2002	2003	2004	
(a)	Bar	Bar	Bar	Bar	None	None	None	None	
(b)	None	None	Bar	Bar	None	None	Bar	Bar	
(c)	None	Bar	None	Bar	None	Bar	None	Bar	

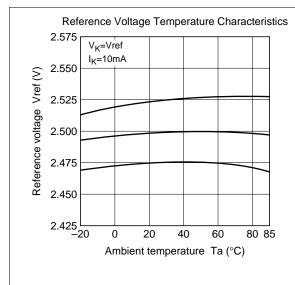
5. The letter (4) shows the production month code (see table below).

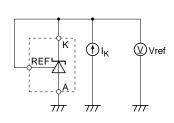
Production month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Marked code	Α	В	С	D	Е	F	G	Н	J	K	L	М

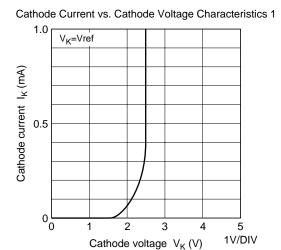
6. The letter (5) shows manufacturing code. For UPAK products.

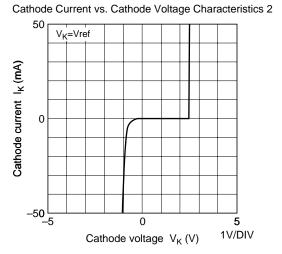
Characteristics Curves

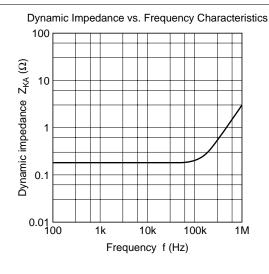
HA17431VLP/VP/VPJ

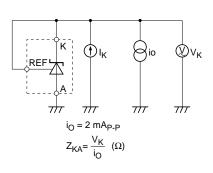




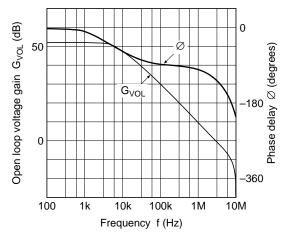


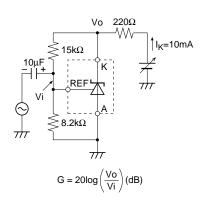




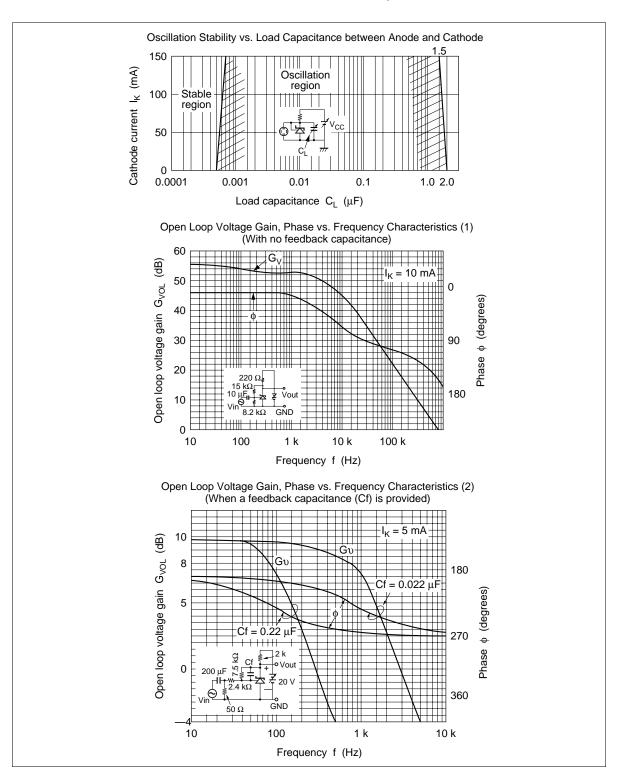


Open Loop Voltage Gain, Phase vs. Frequency Characteristics

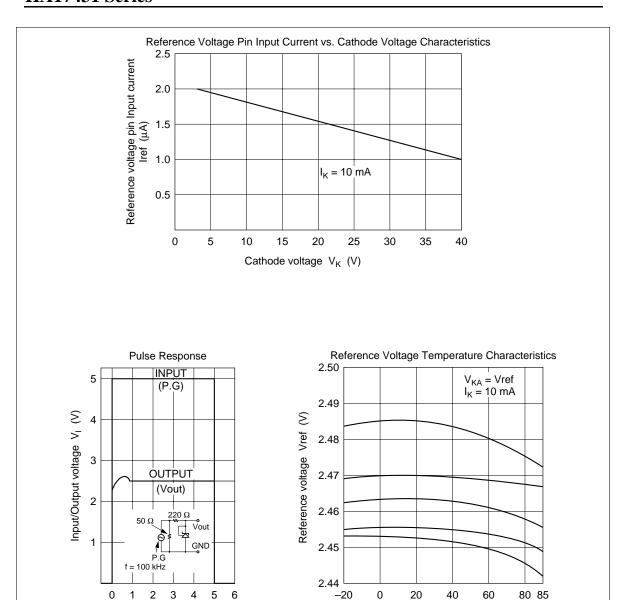




HA17431PJ/PAJ/FPJ/FPAJ/P/PA/UA/UPA/FP/FPA/PNAJ, HA17432UA/UPA

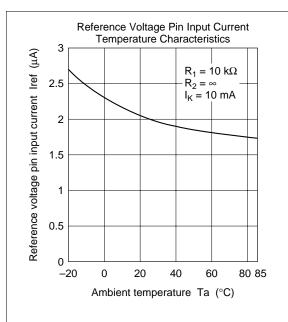


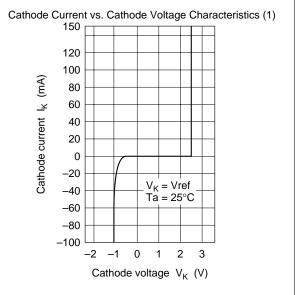
HITACHI

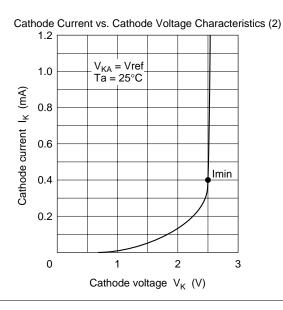


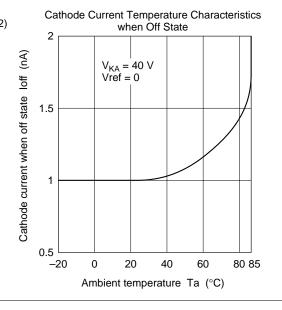
Ambient temperature Ta (°C)

Time t (µs)









Application Examples

As shown in the figure on the right, this IC operates as an inverting amplifier, with the REF pin as input pin. The open-loop voltage gain is given by the reciprocal of "reference voltage deviation by cathode voltage change" in the electrical specifications, and is approximately 50 to 60 dB. The REF pin has a high input impedance, with an input current Iref of 3.8 μ A Typ (V version: Iref = 2 μ A Typ). The output impedance of the output pin K (cathode) is defined as dynamic impedance Z_{KA} , and Z_{KA} is low (0.2 Ω) over a wide cathode current range. A (anode) is used at the minimum potential, such as ground.

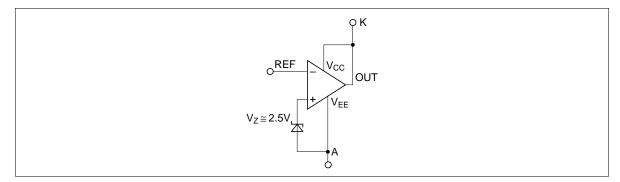


Figure 1 Operation Diagram

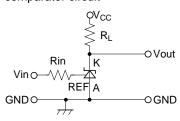
Application Hints

No.	Application Example	Description
1	Reference voltage generation circuit Vin O K Vout	This is the simplest reference voltage circuit. The value of the resistance R is set so that cathode current $I_{\rm K} \ge 1$ mA.
		Output is fixed at Vout \cong 2.5 V.
	GND O GND	The external capacitor C_L ($C_L \ge 3.3~\mu F$) is used to prevent oscillation in normal applications.
2	Variable output shunt regulator circuit	This is circuit 1 above with variable output provided.
	$Vin O - VV - Iref K$ $R_1 > Iref K$ $R_2 > A$ $R_2 > A$ $R_2 > A$ $R_2 > A$ $R_3 > A$ $R_4 > C$ $R_5 > C$ $R_7 > C$ R_7	Here, Vout $\cong 2.5 \text{ V} \times \frac{(R_1 + R_2)}{R_2}$ Since the reference input current Iref = 3.8 μ A Typ (V version: Iref = 2 μ A Typ) flows through R_1 , resistance values are chosen to allow the resultant voltage drop to
	GNDO + + OGND	be ignored.

Application Hints (cont)

No. Application Example

3 Single power supply inverting comparator circuit



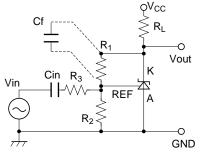
Description

This is an inverting type comparator with an input threshold voltage of approximately 2.5 V. Rin is the REF pin protection resistance, with a value of several $k\Omega$ to several tens of $k\Omega.$

 $R_{_L}$ is the load resistance, selected so that the cathode current $I_{_K} \! \geq \! 1$ mA when Vout is low.

Condition	Vin	Vout	IC
C1	Less then 2.5 V	V _{CC} (V _{OH})	OFF
C2	2.5 V or more	Approx. 2 V (V _{OI})	ON

4 AC amplifier circuit



Gain G =
$$\frac{R_1}{R_2 // R_3}$$
 (DC gain)

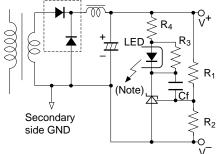
Cutoff frequency fc =
$$\frac{1}{2\pi \text{ Cf } (R_1 /\!/ R_2 /\!/ R_3)}$$

This is an AC amplifier with voltage gain $G = -R_1 / (R_2//R_3)$. The input is cut by capacitance Cin, so that the REF pin is driven by the AC input signal, centered on 2.5 $V_{\rm DC}$.

 $\rm R_2$ also functions as a resistance that determines the DC cathode potential when there is no input, but if the input level is low and there is no risk of Vout clipping to $\rm V_{CC}$, this can be omitted.

To change the frequency characteristic, Cf should be connected as indicated by the dotted line.

5 Switching power supply error amplification circuit



V
Note: LED : Light emitting diode in photocoupler

R3 : Bypass resistor to feed IK(>Imin) when LED current vanishes R4 : LED protection resistance This circuit performs control on the secondary side of a transformer, and is often used with a switching power supply that employs a photocoupler for offlining.

The output voltage (between V+ and V-) is given by the following formula:

Vout
$$\cong$$
 2.5 V $\times \frac{(R_1 + R_2)}{R_2}$

In this circuit, the gain with respect to the Vout error is as follows:

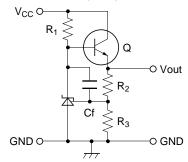
$$G = \frac{R_2}{(R_1 + R_2)} \times \left[\frac{\text{HA17431 open}}{\text{loop gain}} \right] \times \left[\frac{\text{photocoupler}}{\text{total gain}} \right]$$

As stated earlier, the HA17431 open-loop gain is 50 to 60 dB.

Application Hints (cont)

No. Application Example

6 Constant voltage regulator circuit



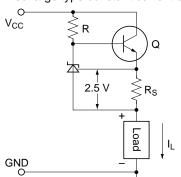
Description

This is a 3-pin regulator with a discrete configuration, in which the output voltage

Vout = 2.5 V ×
$$\frac{(R_2 + R_3)}{R_3}$$

 $R_{\scriptscriptstyle 1}$ is a bias resistance for supplying the HA17431 cathode current and the output transistor Q base current.

7 Discharge type constant current circuit



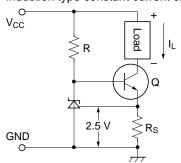
This circuit supplies a constant current of

$$I_L \cong \frac{2.5 \text{ V}}{R_S}$$
 [A] into the load. Caution is required

since the HA17431 cathode current is also superimposed on $I_{\rm l}$.

The requirement in this circuit is that the cathode current must be greater than Imin = 1 mA. The I_L setting therefore must be on the order of several mA or more.

8 Induction type constant current circuit



In this circuit, the load is connected on the collector side of transistor Q in circuit 7 above. In this case, the load floats from GND, but the HA17431 cathode current is not superimposed on I_L , so that I_L can be kept small (1 mA or less is possible). The constant current value is the same as for circuit 7 above:

$$I_L \cong \frac{2.5 \text{ V}}{R_S}$$
 [A]

Design Guide for AC-DC SMPS (Switching Mode Power Supply)

Use of Shunt Regulator in Transformer Secondary Side Control

This example is applicable to both forward transformers and flyback transformers. A shunt regulator is used on the secondary side as an error amplifier, and feedback to the primary side is provided via a photocoupler.

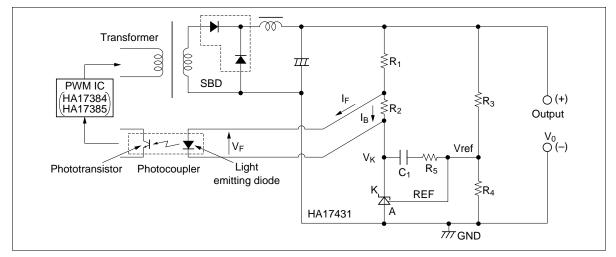


Figure 2 Typical Shunt Regulator/Error Amplifier

Determination of External Constants for the Shunt Regulator

DC characteristic determination: In figure 2, R_1 and R_2 are protection resistor for the light emitting diode in the photocoupler, and R_2 is a bypass resistor to feed I_K minimum, and these are determined as shown below. The photocoupler specification should be obtained separately from the manufacturer. Using the parameters in figure 2, the following formulas are obtained:

$$R_1 = \frac{V_0 - V_F - V_K}{I_F + I_B}$$
, $R_2 = \frac{V_F}{I_B}$

 V_K is the HA17431 operating voltage, and is set at around 3 V, taking into account a margin for fluctuation. R_2 is the current shunt resistance for the light emitting diode, in which a bias current I_B of around 1/5 I_F flows.

Next, the output voltage can be determined by R3 and R4, and the following formula is obtained:

$$V_0 = \frac{R_3 + R_4}{R_4} \times Vref, Vref = 2.5 V Typ$$

The absolute values of R_3 and R_4 are determined by the HA17431 reference input current Iref and the AC characteristics described in the next section. The Iref value is around 3.8 μ A Typ. (V version: 2 μ A Typ)

AC characteristic determination: This refers to the determination of the gain frequency characteristic of the shunt regulator as an error amplifier. Taking the configuration in figure 2, the error amplifier characteristic is as shown in figure 3.

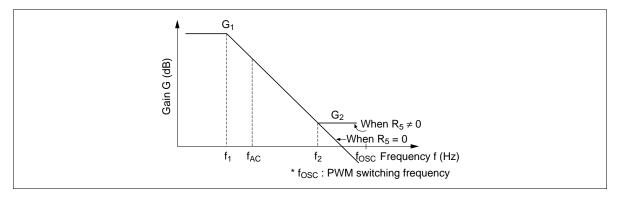


Figure 3 HA17431 Error Amplification Characteristic

In Figure 3, the following formulas are obtained:

Gain

 $G_1 = G_0 \approx 50 \text{ dB to } 60 \text{ dB (determined by shunt regulator)}$

$$G_2 = \frac{R_5}{R_3}$$

Corner frequencies

$$f_1 = 1/(2\pi C_1 G_0 R_3)$$

$$f_2 = 1/(2\pi C_1 R_5)$$

 G_0 is the shunt regulator open-loop gain; this is given by the reciprocal of the reference voltage fluctuation $\Delta V ref/\Delta V_{KA}$, and is approximately 50 dB.

Practical Example

Consider the example of a photocoupler, with an internal light emitting diode $V_F = 1.05$ V and $I_F = 2.5$ mA, power supply output voltage $V_2 = 5$ V, and bias resistance R_2 current of approximately 1/5 I_F at 0.5 mA. If the shunt regulator $V_K = 3$ V, the following values are found.

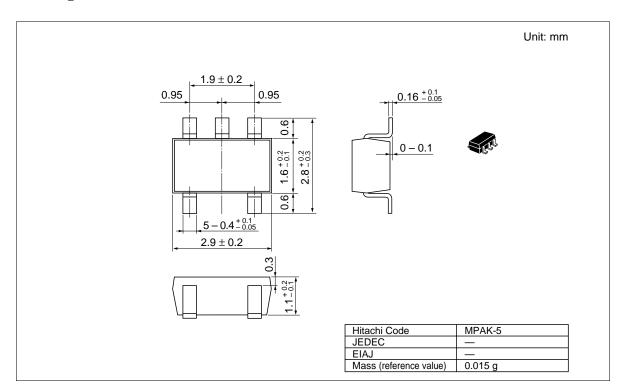
R₁ =
$$\frac{5V - 1.05V - 3V}{2.5\text{mA} + 0.5\text{mA}}$$
 = 316(Ω) (330Ω from E24 series)
R₂ = $\frac{1.05V}{0.5\text{mA}}$ = 2.1(kΩ) (2.2kΩ from E24 series)

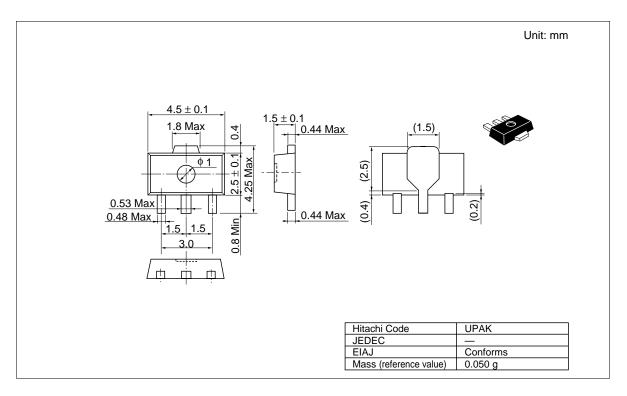
Next, assume that $R_3=R_4=10~k\Omega$. This gives a 5 V output. If $R_5=3.3~k\Omega$ and $C_1=0.022~\mu F$, the following values are found.

$$G_{_2}$$
 = 3.3 k Ω / 10 k Ω = 0.33 times (–10 dB)
$$f_{_1}$$
 = 1 / (2 \times π \times 0.022 μ F \times 316 \times 10 k Ω) = 2.3 (Hz)

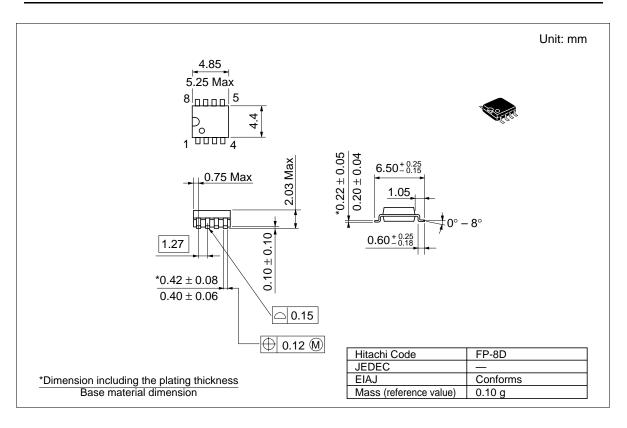
$$\rm f_2$$
 = 1 / (2 \times π \times 0.022 μF \times 3.3 $k\Omega)$ = 2.2 (kHz)

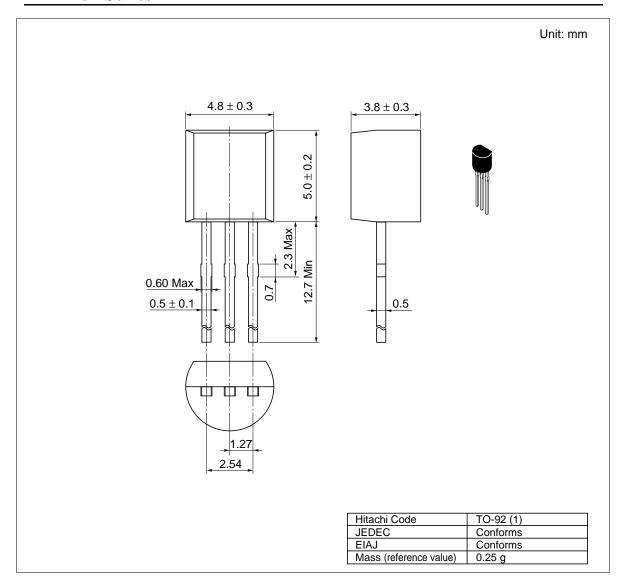
Package Dimensions

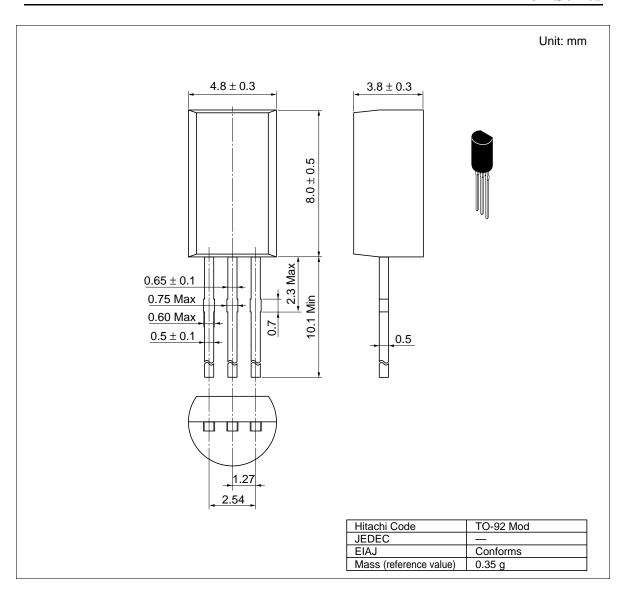




HITACHI







Cautions

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

11TACH

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

NorthAmerica http:semiconductor.hitachi.com/ URL Europe http://www.hitachi-eu.com/hel/ecg

Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD_Frame.htm http://www.hitachi.com.hk/eng/bo/grp3/index.htm

http://www.hitachi.co.jp/Sicd/indx.htm Japan

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive. San Jose CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road

Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281

Copyright ' Hitachi, Ltd., 1998. All rights reserved. Printed in Japan.

Telex: 40815 HITEC HX

HITACHI